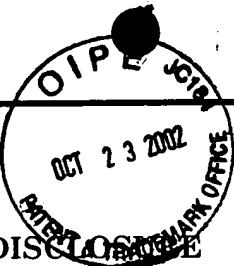


FORM PTO/SB/08A/B (10-01)  
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INFORMATION DISCLOSURE

STATEMENT BY APPLICANT

(use as many sheets as necessary)

Attorney Docket Number 45368/MJM/A717

Application Number 09/516,004

Filing Date February 29, 2000

Applicant(s) Isik C. Kizilyalli, et al.

Group Art Unit 2811

Examiner Name O. Nadav

U.S. PATENT DOCUMENTS

EXAMINER INITIALS	Cite No. <sup>1</sup>	DOCUMENT NUMBER Number - kind code <sup>2</sup> . (If known)	PUBLICATION DATE MM-DD-YYYY	NAME OF PATENTEE
ON		4,468,855	09-04-1984	Sasaki
ON		5,956,603	09-21-1999	Talwar et al.

FOREIGN PATENT DOCUMENTS

EXAMINER INITIALS	Cite No. <sup>1</sup>	Foreign Patent Document Country Code <sup>3</sup> - Number <sup>4</sup> - Kind Code <sup>5</sup> (If known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	T <sup>6</sup> (✓)
ON		GB 2 133 618 A	07-25-1984	The General Electric Company	

OTHER DOCUMENTS

EXAMINER INITIALS	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article, title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.
ON		TSUKAMOTO H. ET AL., "Selective Laser Annealing (SELA) Used in the Fabrication of sub-0.1 $\mu$ m MOSFETs"; Solid State Electronics, Elsevier Science Publishers, Barking, GB; vol. 42, no. 4; 1 April 1998 (1998-04-01); pages 547-556
ON		FOWLER A.B. ET AL.; "Selective Laser Annealing Through Quarter- and Half-Wave Coatings"; IBM Technical Disclosure Bulletin, IBM Corp. New York, US; vol 22, no. 12; May 1980 (1980-05); pages 5473-5474
ON		Partial European Search Report; 5 pages.

EXAMINER SIGNATURE	DATE CONSIDERED
ON	5/30/03

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